## NSN 5961-00-410-3979

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-410-3979 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -300.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and -300.0 collector to emitter voltage/static/base open and -8.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** Between 1.50 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**